ESL0580QFN4

Pin-Schottky Diode Limiter 0.5 to 8.0 GHz



Applications

General purpose power protection Ideal for commercial and industrial applications

Technical Characteristics

Product Features

Power Handling: 1 Watt CW

Internal DC block

Broadband frequency response

Low cost QFN 4mm leadless RoHS compliant package

Hermetically sealed

Excellent VSWR

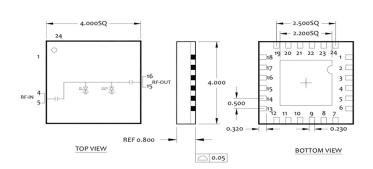
Storage Temperature:	-65 to +125°
Operating Temperature:	-45 to +95°
Maximum input power:	1 Watt CW
Specifications @ [°C]	+25° C

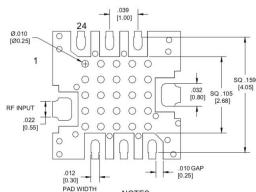
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Electrical Specifications

Parameters	Freq. (GHz)	Min.	Typical	Max.	Units
Insertion Loss	0.5 to 8.0 GHz		0.8	1.8	dB
VSWR	0.5 to 8.0 GHz		1.25:1	2.2:1	
Leakage Power (CW)	0.5 to 8.0 GHz		14.0	16.0	dBm
Limiting Threshold	0.5 to 8.0 GHz		6.0		dBm
CW Power Handling			1.0	2.0	watts
Operating Temperature		-25		90	C°

QFN 4mm Outline Drawing





NOTES: 1. MATERIAL: ROGERS 4350, 10 MIL THICK 2, DIMENSIONS ARE IN INCHES[MM]

NOTES:

1. Typical values are measured at +25°C

2. Pins 4 & 5 - RF input, Pins 15 & 16 - RF output

About EclipseMDI

ECLIPSE Microdevices is located in San Jose, California. ECLIPSE has been developing high performance analog semiconductors for use in wireless radio frequency (RF), microwave, and millimeter wave for commercial and industrial applications. ECLIPSE has formed a strategic alliances - with foundries that features leading state-of-the-art process technologies and with manufacturing facilities for high-volume production of innovative RFIC's.

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Product Export Classification

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